

12-ch. phototransistor array 0.60mm optical pitch on plastic SMD package

General Description

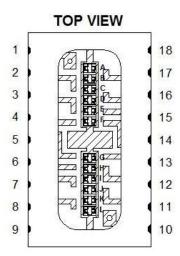
OIT6C consists in two silicon phototransistor's monolithic arrays. The phototransistors have a common collector on the back substrate, which is tied to two single pads and every emitter is accessible to specific pad. The optical pitch of the array is 0.60 mm, the LCC package electrical pitch is 1.27 mm. The active area of each element is 0.20×0.45 mm².

The advantages of this product are the high uniformity of the silicon sensors, due to the monolithic construction and to the extremely controlled microelectronic process, the high stability of the signal and the high optical responsivity, due to the antireflective coating deposited on the phototransistor's areas.

The packaging method is oriented to industrial harsh applications, which means high temperature range, high stability in time and very high uniformity of the silicon cells.

Applications

Optical encoders
Incremental encoders
12 bit absolute encoders
Optical Receivers
Controls/drives





Features

- High uniformity of silicon cells
- High transparency resin
- High gain
- Reference holes for precise mounting
- 0.6 mm optical pitch
- RoHS compliant

Pin Functions

No.	Name	Function
1	ΑE	Phototransistor A Emitter
2	CE	Phototransistor C Emitter
3	EE	Phototransistor E Emitter
4	N.C.	Not connected
5	N.C.	Not connected
6	GE	Phototransistor G Emitter
7	ΙE	Phototransistor I Emitter
8	KE	Phototransistor K Emitter
9	CC	Common collector
10	LE	Phototransistor L Emitter
11	JE	Phototransistor J Emitter
12	HE	Phototransistor H Emitter
13	N.C.	Not connected
14	N.C.	Not connected
15	FE	Phototransistor F Emitter
16	DE	Phototransistor D Emitter
17	BE	Phototransistor B Emitter
18	CC	Common collector

Ordering information

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ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Min	Max	Unit
TA	Operating Temperature Range	-40	85	°C
Ts	Storage Temperature	-40	85	°C
T _{Sol}	Lead Temperature (solder) 3s		230	°C
V _{R(BR)}	Breakdown Voltage Collector-Emitter @ T _A =25°C I _B =100nA I _C =1mA	50		V
P _D	Power Dissipation @ T _A =25°C		150	mW

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rated conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

 $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _D	Dark Current	V _R =10V		5	100	nA
Rλ	Responsivity	V _{CE} =5V λ=880nm	0.5			A/W
λ_{p}	Peak Responsivity	V _{CE} =5V		750		nm
Δλ	Spectral Bandwidth @ 50%	V _{CE} =5V	500		950	nm
l _{ec0}	Emitter-Collector Current	V _{CE} =7.7V		0.1	100	μA
I _{ce0}	Collector-Emitter Current	V _{CE} =52V		0.1	100	μΑ
H _{FE}	Gain	Vcc=5V Ic=2mA	500	1100	1500	
V _{CE(sat)}	Saturation Voltage	I _E =2mA I _B =20µA		80	200	mV
I _{C(on)}	On-state Collector Current	V _{CE} =5V E _E =1.0mW/cm ²		1		mA

AC SWITCHING CHARACTERISTICS

 $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t_R	Rise Time	V_{CC} =5 V I_{C} =1 mA R_{1} =1 $k\Omega$		10		μs
t _F	Fall Time	V_{CC} =5 V I_{C} =1 mA R_1 =1 $k\Omega$		11		μs

MECHANICAL CHARACTERISTICS

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Α	Phototransistor Active Area			0.09		mm²
L	Length of the Active Area			0.2		mm
W	Width of the Active Area			0.45		mm

PACKAGE CHARACTERISTICS

Symbol	Parameter	Value	Unit
SF	Pad Surface Finishing	GOLD	
SL	Pad Shelf Life	6	months
MSL	Moisture Sensitive Level ‡	3	level

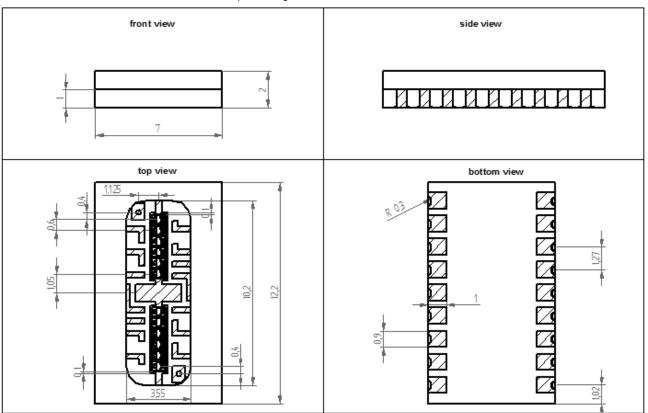


2 http://www.optoi.com/

 $[\]ddagger$ According to Jedec standard J-STD-020D.1

MECHANICAL DIMENSIONS

Units=mm Mechanical tolerance=+/-0.2mm Die positioning tolerance=+/-0.030mm



TYPICAL PERFORMANCE CURVES

Figure 1 – Output voltage Vs Temperature

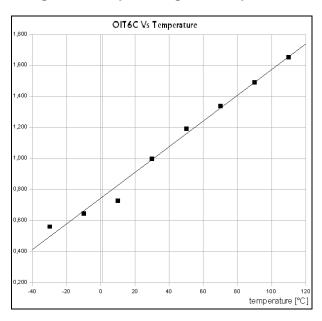
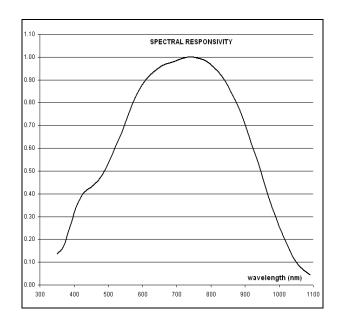


Figure 2 - Normalized spectral responsitivity



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